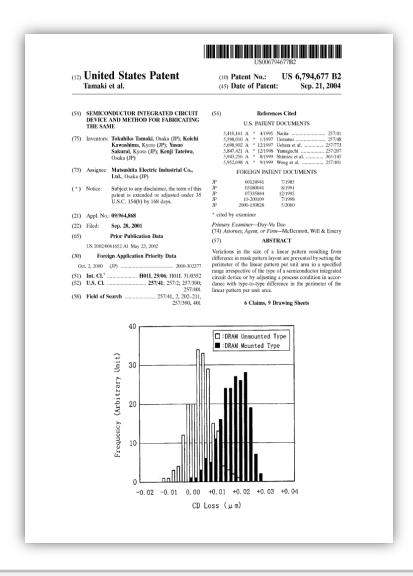
# **EXHIBIT A**

#### Case<u>us 16,704,00290 MNV i Brocuerent 11 34s, 1 n Filord 5636/28/148 i BBBQA MIDN 1950 Pages/20#8</u> 3153



#### **Title**

SEMICONDUCTOR INTEGRATEI CIRCUIT DEVICE AND METHOD FABRICATING THE DEVICE

# **Application Date**

Sep. 28, 2001

# **Priority Date**

Oct. 2, 2000

#### **Patent Date**

Sep. 21, 2004

#### **Inventor**

Tokuhiro Tamaki et al

### **Claims**



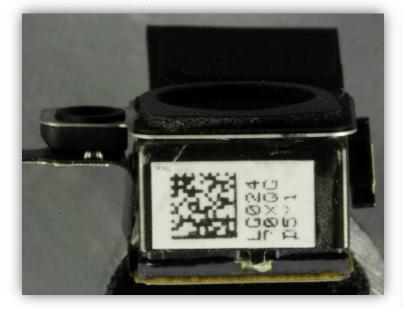
#### Caseus:16,794,00290-MNV is acumentil 31s, In File vist 3 (28) 1 shi b 3 aga si p n 1950 Pages / 20 / 48 | 3154

- 1. A semiconductor integrated circuit device comprising:
- (A) a first circuit pattern having (B) a first linear pattern and placed in (C) a region in which a group of elements repetitive pattern are formed; and
- (D) a second circuit pattern having (E) a second linear pattern and placed in (F) a region in which components oth group of elements are formed,
- (G) a dummy pattern being inserted in (F) the region in which (D) the second circuit pattern is placed such that a su of (B) the first linear pattern, (E) the second linear pattern, and (G) the dummy pattern per unit area is equal to or perimeter of (B) the first linear pattern per unit area.
- 2. The semiconductor integrated circuit device of claim 1, wherein (C) the group of elements are (H) memories.
- 4. A semiconductor integrated circuit device comprising:
- (A) a first circuit pattern having (B) a first gate electrode pattern and placed in (C) a memory circuit region; and (D) a second circuit pattern having (E) a second gate electrode pattern and placed in (F) a logic circuit region, (G) a dummy pattern being inserted in (F) the logic region in which (D) the second circuit pattern is placed
- such that a sum perimeter of (B) the first gate electrode pattern, (E) the second gate electrode pattern, and (G) the pattern per unit area is equal to or less than a perimeter of (B) the first gate electrode pattern per unit area.
- 5. The semiconductor integrated circuit device of claim 4, wherein (G) the dummy pattern has (H) a rectangular like shape.

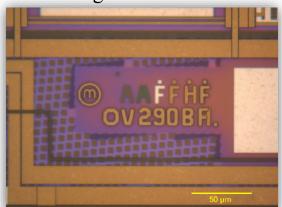


#### Caseu<u>\$116,704,00290-MNVishocuenentil@ls.lin.Filerd563628018niBBaga MpN195</u>DPaged/20#83155

#### Camera Module









OmniVision
OV5650
5 Mp, 1.75 µm Pixel Pitch
Second Generation
Back Illuminated (BSI) CMOS
Image Sensor from Apple iPhone 4

**Imager Process Review** 

For comments, questions, or more information about this report, or for any additional techn needs concerning semiconductor and electronics technology, please call Sales at Chipworl

3885 Richmond Road, Suite 500, Ottawa, ON K2H 5B7, Canada Tel: 613.829.0414 Fax: 613.829.0515 www.chip



#### Case<u>us 16,704,00290 MNV i Document 11 21s, In Filord 5131/2014 Rib Baga Sud N1950 Pages/20148</u> 3156

Manufacturer	OmniVision Technologies, Inc.
Foundry	TSMC
Part number	OV5650
Туре	Back illuminated CMOS image sensor
Camera module size (length x width x height)	9.2 mm x 9.2 mm x 6.2 mm
Camera module pads	29
Date code	None
Die markings	(m) AAFFHF OV290BF
Die size (from die edge)	6.06 mm x 6.58 mm (39.9 mm <sup>2</sup> )
Final die thickness (image sensor die + silicon chip carrier)	200 μm
Image sensor substrate thickness	2.1 µm
Available/connected die bond pads	64/43
Bond pad pitch	350 μm
Bond pad window	67 μm x 145 μm
Process type	CMOS
Number of metal layers	4
Number of poly layers	1
Minimum transistor gate length	0.12 μm
Minimum metal pitch (pixel array)	0.30 μm
Contacted gate pitch	0.36 μm
NAND cell size	1.6 μm by 4.3 μm (6.9 μm²)
6T SRAM cell size	1.3 μm x 1.8 μm (2.3 μm <sup>2</sup> )
Process generation	0.11 μm (TSMC half-node)
Feature measured to determine process generation	Contacted gate pitch, metal pitch



# DOCKET

# Explore Litigation Insights



Docket Alarm provides insights to develop a more informed litigation strategy and the peace of mind of knowing you're on top of things.

## **Real-Time Litigation Alerts**



Keep your litigation team up-to-date with **real-time** alerts and advanced team management tools built for the enterprise, all while greatly reducing PACER spend.

Our comprehensive service means we can handle Federal, State, and Administrative courts across the country.

#### **Advanced Docket Research**



With over 230 million records, Docket Alarm's cloud-native docket research platform finds what other services can't. Coverage includes Federal, State, plus PTAB, TTAB, ITC and NLRB decisions, all in one place.

Identify arguments that have been successful in the past with full text, pinpoint searching. Link to case law cited within any court document via Fastcase.

### **Analytics At Your Fingertips**



Learn what happened the last time a particular judge, opposing counsel or company faced cases similar to yours.

Advanced out-of-the-box PTAB and TTAB analytics are always at your fingertips.

#### API

Docket Alarm offers a powerful API (application programming interface) to developers that want to integrate case filings into their apps.

#### **LAW FIRMS**

Build custom dashboards for your attorneys and clients with live data direct from the court.

Automate many repetitive legal tasks like conflict checks, document management, and marketing.

#### **FINANCIAL INSTITUTIONS**

Litigation and bankruptcy checks for companies and debtors.

#### **E-DISCOVERY AND LEGAL VENDORS**

Sync your system to PACER to automate legal marketing.

